

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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OPB917 Series

Features:

- Low power consumption
- Data rates to 250 kBaud
- Choice of two logic states and two electrical outputs
- 24" (610 mm) minimum 26 AWG UL listed wires
- Slot width 0.20" (5.08 mm)
- Slot Depth 0.86" (21.84 mm)





Description:

The OPB917 series of Photologic® photo integrated circuit switches provide optimum flexibility. Each switch consists of an infrared Light Emitting Diode (LED) and a Photologic® photo integrated circuit, mounted in an opaque housing with clear windows for dust protection. The deep slot allows for a longer reach of the optical path from the 0.650" (16.5 mm) mounting plane. Internal apertures are 0.010" x .060" (.25 mm x 1.52 mm) for the Photologic's "S" side and 0.05" x 0.06" (1.27 mm x 1.52 mm) for the LED "E" side.

Devices in this series exhibit stable performance over supply voltages ranging from 4.5 V to 16.0 V, and may be specified as buffered or inverted with an internal 10 k Ω pull-up resistor or open collector output. Devices are TTL/LSTTL compatible and can drive up to 10 TTL loads.

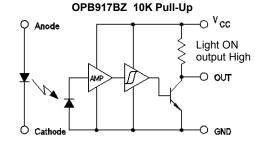
Custom electrical, wire or cabling are available. Contact your local representative or OPTEK for more information.

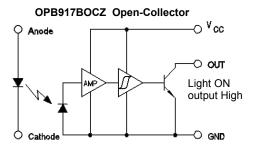
Applications:

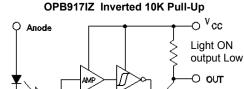
- Mechanical switch replacement
- Speed indication (tachometer)
- Mechanical limit indication
- Edge sensing

Ordering Information							
Part Number			Slot Width/ Depth	Aperture Emitter/ Sensor	Lead Length / Wire		
OPB917BZ		10K Pull-Up		0.05" / 0.01"	24" / 26 AWG Wire		
OPB917IZ	000	Inv-10K Pull-Up	0.200" /				
OPB917BOCZ	880 nm	Open-Collector	0.635"				
OPB917IOCZ		Inv-Open-Collector					

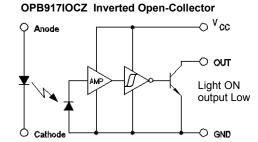








O GND





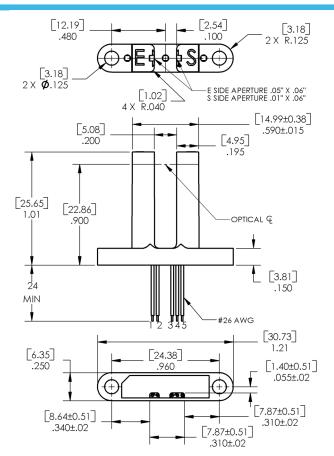
General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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OPB917 Series



Color	Description				
Red	Anode				
Black	Cathode				
Green	Ground				
Blue	Output				
White	V _{CC}				

[MILLIMETERS]
DIMENSIONS ARE IN: INCHES

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)				
Storage & Operating Temperature Range	-40°C to +80°C			
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] (1)	260°C			
Input Infrared LED				
Supply Voltage, V _{CC} (not to exceed 3 seconds)	18 V			
Input Diode Power Dissipation ⁽²⁾	100 mW			
Forward DC Current	50 mA			
Output Photologic®				
Voltage at Output Lead (Open Collector Output)	35 V			
Diode Reverse DC Voltage	2 V			
Output Photologic® Power Dissipation ⁽³⁾	90 mW			

Notes

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly 1.33 mW/°C above 25°.
- (3) Derate linearly 2.50 mW/°C above 25°.
- (4) Normal application would be with light source blocked, simulated by $I_F = 0$ mA.
- (5) All parameters tested using pulse technique.



OPB917 Series

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diod	e	'				1
V _F	Forward Voltage	-	1.3	1.8	V	I _F = 20 mA
I _R	Reverse Current	-	-	100	μA	V _R = 2 V, T _A = 25° C
Output Pho	otologic® Sensor					
V _{CC}	Operating DC Supply Voltage	4.5	-	16	V	-
I _{CCL}	Low Level Supply Current: Buffered with 10k pull-up ⁽¹⁾ Buffered Open-Collector Output ⁽¹⁾	-	-	7	mA	V_{CC} = 16 V, I_F = 0 mA, No Output Load
	Inverted with 10k pull-up: Inverted Open-Collector Output	-	-	7	mA	V_{CC} = 16 V, I_F = 10 mA, No Output Load
I _{CCH}	High Level Supply Current: Buffered with 10k pull-up Buffered Open-Collector Output	-	-	6	mA	V_{CC} = 16 V, I_F = 10 mA, No Output Load
	Inverted with 10k pull-up: Inverted Open-Collector Output ⁽¹⁾	-	-	6	mA	V _{CC} = 16 V, I _F = 0 mA, No Output Load
V _{OL}	Low Level Output Voltage: Buffered with 10k pull-up Buffered Open-Collector Output		- -	0.4 0.4	٧	V_{CC} = 4.5 V, I_{OL} = 0 mA, I_F = 0 mA V_{CC} = 4.5 V, I_{OL} = 16 mA, I_F = 0 mA
	Inverted with 10k pull-up: Inverted Open-Collector Output	-	-	0.4 0.4	V	$V_{CC} = 4.5 \text{ V}, I_{OL} = 0 \text{ mA}, I_F = 10 \text{ mA}$ $V_{CC} = 4.5 \text{ V}, I_{OL} = 16 \text{ mA}, I_F = 10 \text{ mA}$
V _{OH}	High Level Output Voltage: Buffered with 10k pull-up Buffered Open-Collector Output	V _{CC} 2.4	Vcc- 1.5	-	٧	. V_{CC} = 4.5 V to 16 V, I_F = 10 mA, No Output Load
	Inverted with 10k pull-up: Inverted Open-Collector Output ⁽¹⁾	V _{CC} 2.4	Vcc- 1.5	-	V	V_{CC} = 4.5 V to 16 V, I_F = 0 mA, No Output Load
I _{ОН}	High Level Output Voltage: Buffered with 10k pull-up Buffered Open-Collector Output	-	1.0	14	μА	$V_{CC} = 4.5 \text{ V}, I_F = 10 \text{ mA}, V_{OH} = 30 \text{ V}$
	Inverted with 10k pull-up: Inverted Open-Collector Output ⁽¹⁾	-	1.0	14	μA	$V_{CC} = 4.5 \text{ V}, I_F = 0 \text{ mA}, V_{OH} = 30 \text{ V}$
I _{F(+)}	LED Positive-Going Threshold Current Buffered with 10k pull-up Buffered Open-Collector Output	-	5	10	mA	V _{CC} = 5 V, I _{OL} = 0 mA
	Inverted with 10k pull-up: Inverted Open-Collector Output ⁽¹⁾	-	5	10	mA	V _{CC} = 4.5 V, I _{OL} = 16 mA

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OPB917 Series

Electrical Characteristics (T _A = 25° C unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
I _{F(+)/} I _{F(-)}	Hysteresis	-	1.5	-	-	V _{CC} = 5 V
t _r t _f	Rise Time, Fall Time	-	50	-	ns	$V_{CC} = 5 \text{ V, I}_F = 0 \text{ or } 10 \text{ mA,}$ $R_L = 300 \Omega \text{ to 5 V, C}_L = 50 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay	-	3	-	μs	$V_{CC} = 5 \text{ V, } I_F = 0 \text{ or } 10 \text{ mA,}$ $R_L = 300 \Omega \text{ to 5 V, } C_L = 50 \text{ pF}$

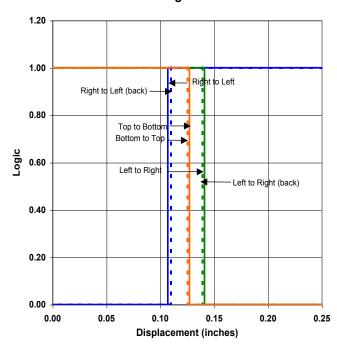
Notes:

- (1) Normal application would be with light source blocked, simulated by $I_F = 0$ mA.
- (2) All parameters tested using pulse technique.

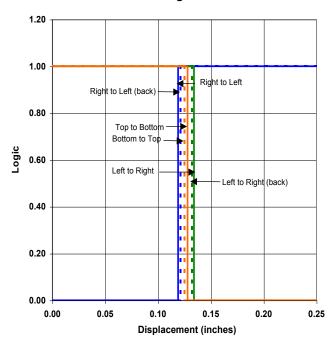




OPB917—Flag Next to Emitter



OPB917—Flag Next to Sensor



OPB917—Flag Middle of Slot

